NSN 5961-01-324-3550



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-324-3550 **Inclosure Material:** Metal **Overall Length:** 1.548 inches **Overall Height:** Between 0.280 inches and 0.350 inches **Overall Width:** 1.105 inches **End Application:** Transmitter group ot-12 (v) tpq-37. Radar, firefinder, an/tpq-36 and an/tpq-37. **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0.3 **Mounting Method:** Unthreaded hole **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage/static/emitter open and 500.0 collector to emitter reverse voltage and 500.0 collector-to-emitter, substaining voltage, base open-circuited and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn. Weapon system essential **Test Data Document:** 05869-723084-53 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-324-3550 Transistor - Page 2 of 2



Fiig:

A110a0